



... for a brighter future

1-Å FEL Oscillator with ERL Beams

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Novosibirsk, Russia

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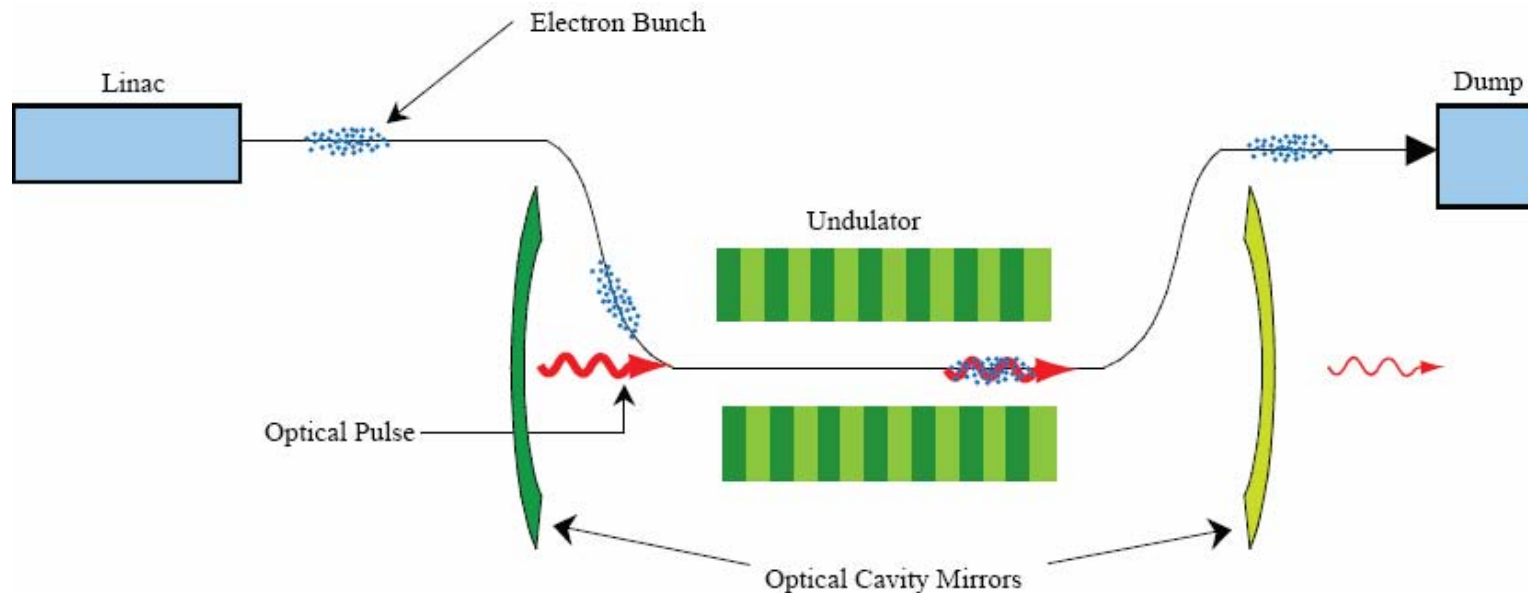
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FELs for $\lambda < 1\text{-\AA}$ Wavelengths

- High-gain FEL amplifier, SASE or HGHG, as an option for future light source providing an enormous jump in peak brightness, became realistic due to advance in gun-linac technology
 - $I_p \sim$ several kA, $\varepsilon_x^n \sim 1$ mm-mr beams
 - LCLS, European X-FEL, SCSS, Fermi, Arc-en-Ciel,..
- Electron beams from guns for another option for FLS, the ERLs, promise to be extreme low-emittance, high average power
 - $I_p \sim 4\text{-}12$ A, $\varepsilon_x^n \sim 0.1$ mm-mr
 - Rep rates upto 1.3 Gz
- We discuss an X-ray FEL *Oscillator* (XFEL-O) for $\lambda < 1\text{-\AA}$ based on high energy ERL beams
 - High peak as well as average brightness & narrow bandwidth

Principles of an FEL Oscillator



■ Small signal gain $G = \Delta P_{\text{opt}} / P_{\text{opt}}$

- Start-up: $(1 + G_0) R_1 R_2 > 1$ (R_1 & R_2 : mirror reflectivity)
- Saturation: $(1 + G_{\text{sat}}) R_1 R_2 = 1$

■ Synchronism

- Spacing between electron bunches = $2L/n$ (L : length of the cavity)

Feedback-Enhanced x-rays

- X-ray FEL Oscillator (XFEL-O) using Bragg reflector was first proposed by Colella and Lucio at a BNL workshop in 1984.
- (This was also when high-gain FEL and SASE was proposed by Bonifacio, Narducci and Pellegrini, independently from Saldin's earlier work)
- Feedback-enhanced x-rays using **electron beams optimized for high-gain amplifiers** have been studied recently:
 - Electron outcoupling scheme by Adams and Materlik (1996)
 - Regenerative amplifier using LCLS beam (Huang and Ruth, 2006)

Main Issues for ERL-based XFEL-O

■ **Electron beams of suitable characteristics**

- Production and recirculation of high quality beams

■ **FEL dynamics**

- Sufficient initial gain
- Coupling of spontaneous emission to coherent mode
- Beam degradation consistent with recirculation path

■ **High reflectivity optical cavity**

- Crystals in backscattering configuration
- Focusing elements
- Outcoupling schemes

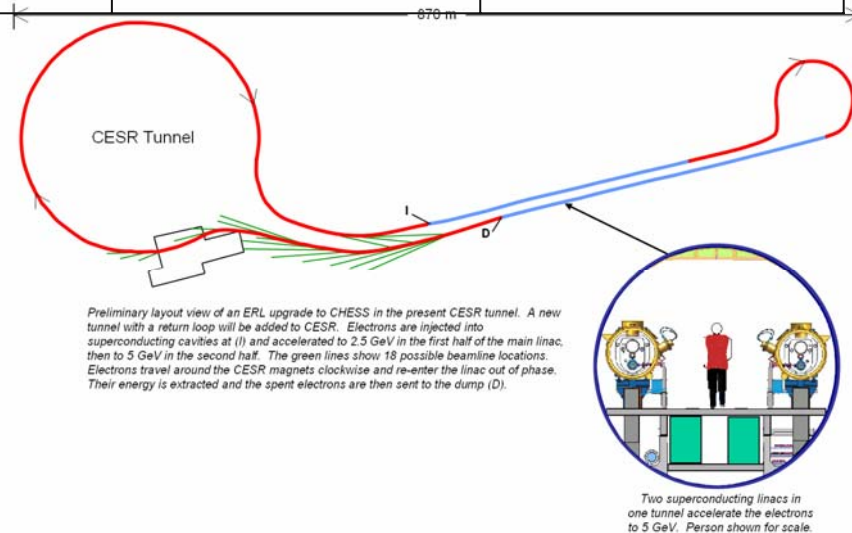
Cornell 5 GeV ERL Parameter scaled to 7 GeV APS II:

G. Hoffstaetter, FLS 2006 Workshop, DESY

	APS Now	High Flux	High Coherence	Ultrashort Pulse
Average Current (mA)	100	100	25	1
Repetition rate (MHz)	0.3 ~ 352	1300	1300	1
Bunch charge (pC)	0.3 ~ 60	0.077	19 (60)**	1
Emittance (nm)	3.1 x 0.025	0.022 x 0.022	0.006 x 0.006	0.37 x 0.37
Rms bunch length (ps)	20 ~ 70	2	2	0.1
Rms momentum spread (%)	0.1	0.02	0.02	0.3

With gun optimization, the charge can be increased to 60 pC

I.V. Bazarov & C.K. Sinclair, PRSTAB,8, 0342002 (2005)



FEL Beam Dynamics

■ Gain calculations

- Analytic formula for low signal gain including diffraction and electron beam profile
- Steady state GENISIS simulation for general intra-cavity power to determine saturation power

■ Time-dependent oscillator simulation by GENO

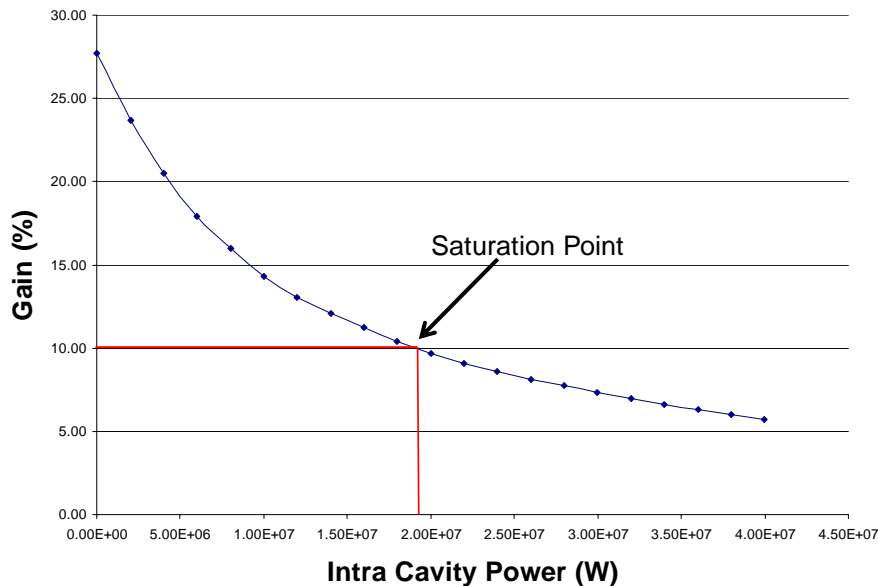
- Extend OPC by adding mirror bandwidth (Reiche)
- Necessary to establish the growth from spontaneous emission

■ Reduce the CPU time by

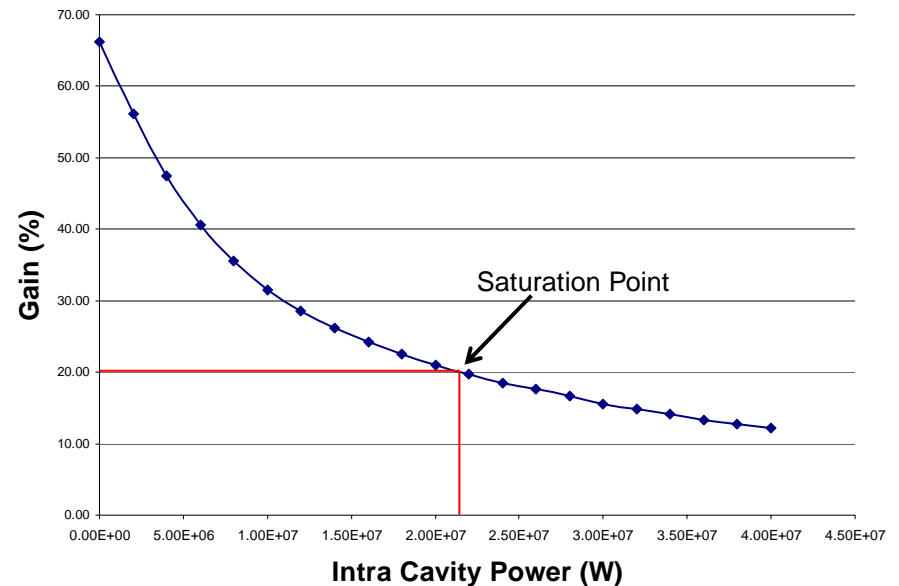
- Modeling a short window (25 fs)
- Tracking a single frequency component for radiation wavefront since other components are outside the crystal bandpass
- About 2 hr for one pass

Saturation: As circulating power increases the gain drops and reach steady state when gain=loss

$E=7\text{GeV}$, $\lambda=1\text{\AA}$
 $Q=19\text{ pC}$ ($I_p=3.8\text{A}$), $N_u=3000$
Mirror reflectivity=90%
Saturation power=19 MW



$E=7\text{GeV}$, $\lambda=1\text{\AA}$
 $Q=40\text{ pC}$ ($I_p=8\text{ A}$), $N_u=3000$
Mirror reflectivity=80%
Saturation power=21 MW



Saturation in about 100-200 passes

Examples of Steady State Calculation

$$\sigma_{\tau}=2 \text{ ps}, \sigma_{\gamma}=1.37, \varepsilon_{xn}=0.82 \cdot 10^{-7} \text{ m}$$

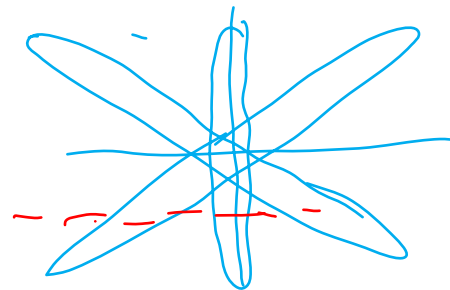
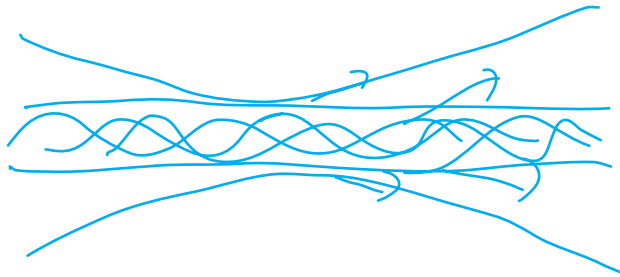
$$Z_R=\beta^*=10\sim 12 \text{ m}$$

$\lambda(\text{\AA})$	E(GeV)	Q (pC)	K	$\lambda_U(\text{cm})$	N_U	G_0 (%)	R_T (%)	P_{sat} (MW)
1	7	19	1.414	1.88	3000	28	90	19
1	7	60	1.414	1.88	3000	~100	83	21
0.84	7.55	19	1.414	1.88	3000	28	90	20
0.84	10	19	2	2.2	2800	45	83	18

Results of GENO Simulation

■ Constant electron focusing ($\beta_{ave}=5.6$ m)

- Steady state gain is ~40% for low charge case (19 pC)
- Exponential growth did not occur-- probably coupling of spontaneous emission to coherent mode is too small



■ No focusing, beam waist at the undulator center ($\beta^* \sim 10$ m) and mode Rayleigh length $\sim \beta^*$

- Smaller gain, but a good coupling to the coherent mode
- High charge case (60 pC): exponential gain and saturation observed
- With 19 pC, growth is not strong—factor 6 over spontaneous after 40 passes (as of 6 AM this morning!)
- Further optimization of electron and mode parameters will be necessary

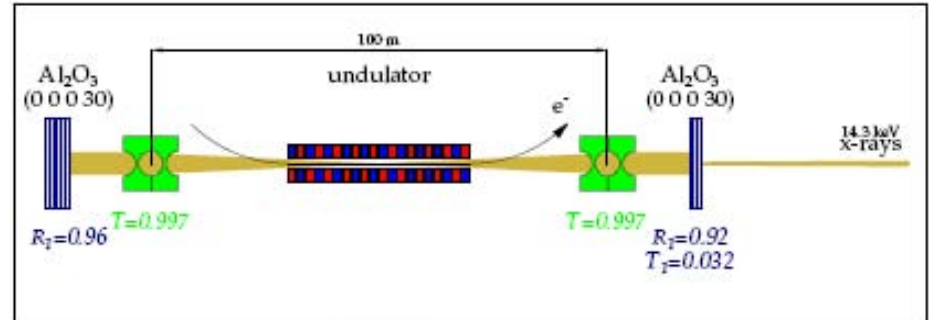
Desired Optics for the X-FEL Oscillator (Y. Shvyd'ko)

- **Reflectivity $R_1 \times R_2 > 90-80\%$**
 - “Pure” diamond or sapphire
- **Transmissivity $T \sim 5\%$**
 - Thin crystal, accompanying diffraction in near BS
- **Focusing elements**
 - Curving crystal can affect reflectivity even for $R \sim 50\text{m}$
 - Grazing incidence mirrors or compound reflective lenses
- **Heat loading is OK to 1 MHz, may be up to 100Mz**
 - Cooling AL_2O_3 to 40 degree

Options for XFEL-O Cavities (Y. Shvyd'ko)

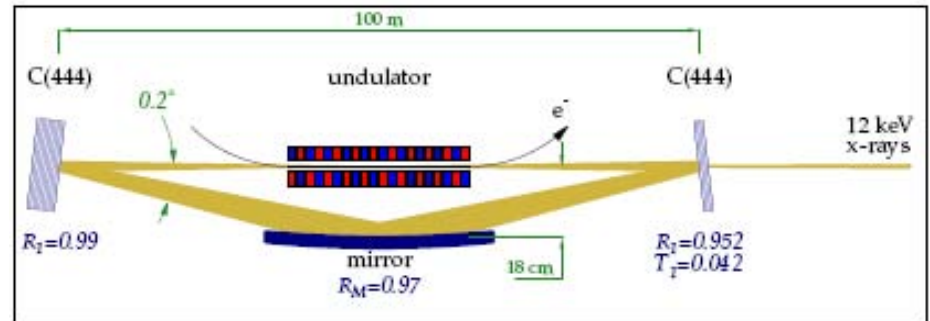
$\text{Al}_2\text{O}_3 \times \text{Al}_2\text{O}_3$ @ 14.3 keV

$R_T=0.87$, $G_{\text{sat}}=15\%$, $T=3\%$



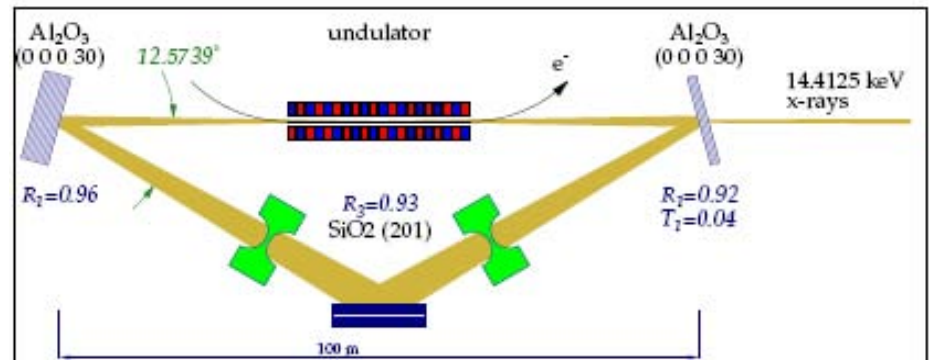
CxCxmirror @ 12.4 keV

$R_T=0.91$, $G_{\text{sat}}=10\%$, $T=4\%$



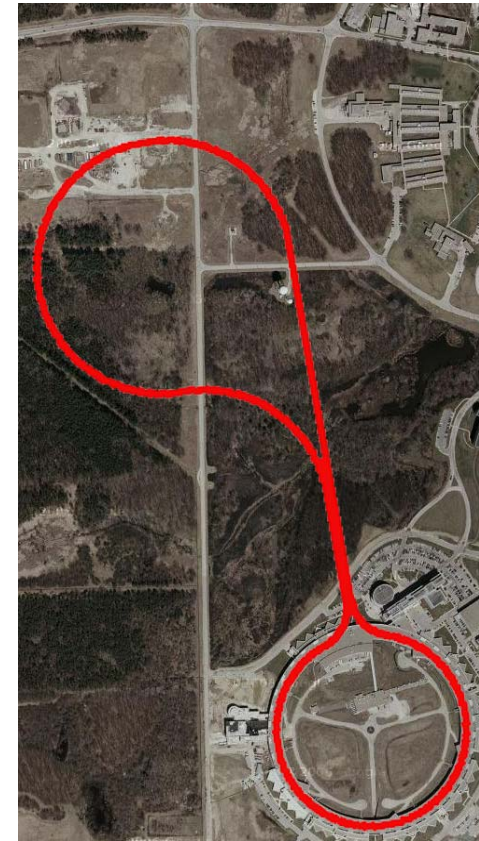
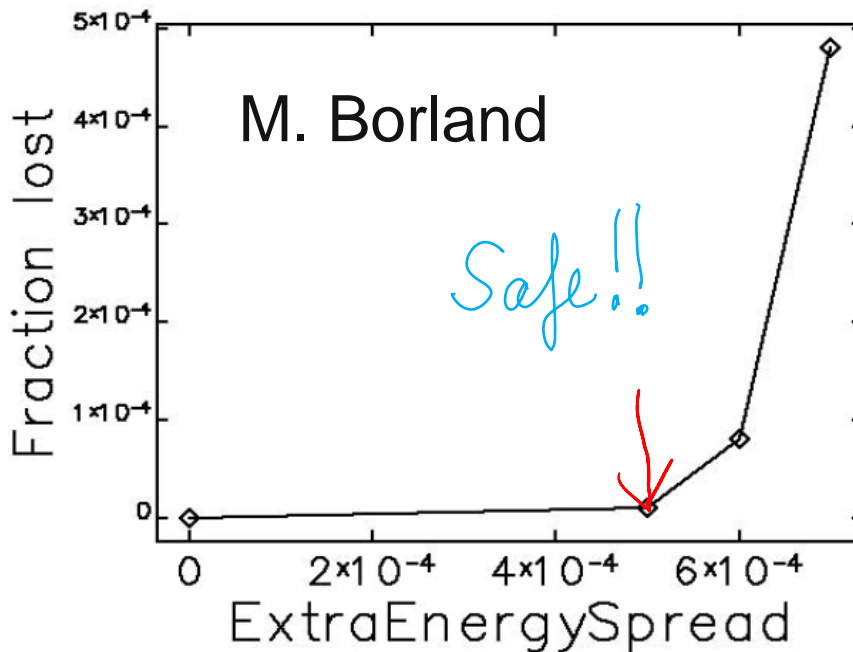
$\text{Al}_2\text{O}_3 \times \text{Al}_2\text{O}_3 \times \text{SiO}_2$ @ 14.4125 keV

$R_T=0.82$, $G_{\text{sat}}=22\%$, $T=4\%$



Energy Acceptance of the Recirculation-Pass for APS-ERL

- Genesis simulation shows that the rms energy spread increases from 0.02% to 0.05% after the FEL interaction
- The ERL return pass can accommodate 0.05% energy spread



Photon Performance of XFEL-O

- Wavelength: 1-Å or shorter, $\epsilon_\gamma=12.4$ keV or higher
- Full transverse coherence
- Full temporal coherence in 1 ps duration
 - $\Delta\nu/\nu=0.3 \cdot 10^{-6}$; $h\Delta\nu=4$ meV
- 10^9 photons ($\sim 1 \mu\text{J}$) /pulse
 - Peak spectral brightness~LCLS
- Rep rate: 1 MHz or higher, limited by crystal heat load, 100MHz?
 - Average brightness 10^{27} ($\rightarrow 10^{29}$) #photons/(mm-mr)²(0.1%BW)
 - 10^3 - 10^5 times higher than ERL based undulator source

Science Drivers for XFEL-O

- Inelastic x-ray scattering (IXS) and nuclear resonant scattering (NRS) are flux limited experiments! *Need more spectral flux in a meV bandwidth!* .
- Undulators at storage rings generate radiation with $\approx 100\text{--}200$ eV bandwidth. Only $\approx 10^{-5}$ is used, the rest is filtered out by meV-monochromators.

Presently @ APS: $\approx 5 \times 10^9$ photons/s/meV (14.4 keV)

- XFEL-O is a perfect x-ray source for:
 - high-energy-resolution spectroscopy (meV IXS, neV NRS, etc.), and
 - imaging requiring large coherent volumes.
 - Expected with XFEL-O $\approx 10^{15}$ photons/s/meV (14.4 keV) with 10^7 Hz repetition rate.

Concluding Remarks

- XFEL-O appears to be feasible with beams expected from future ERLs
- It is a promising and powerful addition to ERL capabilities
- Application areas: nuclear resonance scattering, coherent imaging, inelastic scattering,...
- This is initial exploration with much room for further optimization.